

Electronic band structure of low-temperature YB_{12} , YB_6 superconductors and layered YB_2 , MgB_2 diborides

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Electronic band structure of boron-rich low-temperature superconductors UB_{12} -like dodecaboride YB_{12} and CaB_6 -like hexaboride YB_6 are investigated using the first-principle FLMO calculations and compared with one for layered YB_2 and the new "medium- T_c " superconductor MgB_2 diborides.

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1. Introduction

The discovery of the superconductivity in MgB_2 ($T_c \approx 40$ K) [1] and creation of promising materials based thereon (in the form of single crystals, ceramics, thin films, tapes and wires, see reviews [2,3]) have attracted a great deal of interest in superconducting properties of other boron-containing phases.

Comparison between different classes of binary (semi- (MB_2) , mono- (MB) , di- (MB_2) , tetra- (MB_4)) and some highest borides (hexa- (MB_6) , dodeca- (MB_{12}) and MB_{66} -like borides), ternary and quaternary borides (review [3]) shows that the majority of known superconductors (SC) are found among low-boron-containing compounds ($B/M \approx 2 - 2.5$), in which B atoms are in the form of isolated groups (atoms) or planar sublattices (boron sheets). The superconducting state is far less typical of highest borides ($B/M \approx 6$) having a structure made up of stable polyhedra of boron atoms (octahedra B_6 (MB_6), icosahedra B_{12} (MB_{12}) or their combination (MB_{66})). Among a large number of these boron-rich phases, the low-temperature superconductivity was observed only for eight compounds: MB_6 ($M = Y, La, Th, Nd$) and MB_{12} ($M = Sc, Y, Zr, Lu$) [3]. It is significant that (i) lower borides of these elements,

in particular Sc and Y diborides, are not SC, and (ii) the stable polymorphism of the elemental boron ($\alpha\text{-}B_{12}$, $\beta\text{-}B_{105}$), which under equilibrium conditions contain the boron polyhedra (icosahedra or "gigantic" icosahedra B_{84}) as structural elements, are semiconductors [4-8]. Only recently it was found that polycrystalline boron (rhombohedral $\beta\text{-}B_{105}$) transforms from a semiconductor to a superconductor ($T_c \approx 11.2$ K) at about 250 GPa [9]. In this work we calculate the electronic band structures of low-temperature SCs - boron-rich phases YB_{12} and YB_6 - and compare them with two representatives of layered AB_2 -type diborides, namely the non-superconducting YB_2 and new "medium- T_c " SC MgB_2 . The results obtained are analyzed in terms of (i) electronic bands, (ii) density of states (DOS) and (iii) site-projected decomposed DOS near the Fermi energy (E_F) of these borides. The Fermi surfaces for YB_2 and MgB_2 are also presented.

2. Structures and computational

The basic structural elements of the cubic dodecaboride YB_{12} are stable polyatomic boron clusters with icosahedral symmetry (B_{12}) similar to that in elemental boron. The structure of the UB_{12} type (space group is $O_h^5\text{-}Fm\bar{3}m$) is formally described in terms of simple rock-salt lattice, where Y occupies Na sites and B_{12} icosahedra

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dra are located in Cl sites, the unit cell contains 52 atoms ($Z = 4$). The atomic positions are 4M (a) 0,0,0; 48B (i) $\frac{1}{2}, x, x$ ($x = 0.17011$ for our self-consistent calculation).

The role of Y and B₁₂ in forming the YB₁₂ band structure can be elucidated by removing Y atoms from the lattice entirely and calculating this hypothetical "dodecaboride" with an empty Y-sublattice (EB₁₂ - E - structure vacancy) and the icosahedral phase (BB₁₂), which is a result of the Y! B substitution.

Yttrium hexaboride has a CaB₆-type structure (space group is O_h¹-Pm 3m). It can be formally described in terms of a simple CsCl lattice, where metal atoms occupy Cs sites, while B₆ octahedra are in Cl sites. The unit cell contains 7 atoms ($Z = 1$). The atomic positions are M (a) 0,0,0; 6B (f) $\frac{1}{2}, \frac{1}{2}, x$ ($x = 0.19538$ for our self-consistent calculation). There are two different B-B distances for intra- and inter-octahedral B-B bonds.

The crystal structure of layered AlB₂-like Mg and Y diborides (space group is D_{6h}¹-P6/mmm) is of an entirely different. It contains graphite-type boron sheets separated by hexagonal close-packed metal layers. Metal atoms are located at the center of hexagons formed by boron atoms. The unit cell contains 3 atoms ($Z = 1$). The atomic positions are M (a): 0,0,0; 2B (d): $\frac{1}{3}, \frac{2}{3}, \frac{1}{2}$ and $\frac{2}{3}, \frac{1}{3}, \frac{1}{2}$. AlB₂-type diborides exhibit a strong anisotropy of B-B bond lengths: the inter-plane distances are considerably higher than in-plane B-B distances. Table 1 lists the lattice parameters of the borides under study both taken from experiments [10] and obtained in our structural relaxation calculations.

The electronic band structures of the above-mentioned yttrium and magnesium borides were calculated using codes [11]. This program employs a scalar relativistic self-consistent full-potential linear muffin-tin method (FLMTO) within the local density approximation (LDA) [12] with allowance for correlation and exchange effects [13] by using the generalized gradient approximation (GGA) [14]. The tetrahedron method was used to calculate the density of states.

3. Results and discussion

3.1. YB₁₂

Fig. 1 displays the energy bands of YB₁₂ as compared with the hypothetical "dodecaboride" EB₁₂ with a vacant Y sublattice. For EB₁₂, the total width of the valence band (VB) is 10.32 eV (without quasi-core B 2s-type bands located at 14 eV below the Fermi level). It includes two groups of occupied hybrid B 2s,2p-like bands (A and B) within the intervals -10.99 - -8.83 and -8.44 - 0 eV, separated by a gap (0.4 eV). The lower bands contain predominantly B 2s-, and the upper bands - B 2p-type contributions. The latter can be separated into three groups depending on the intra-atomic bonds in the crystal. There are two types of bonding B 2s,2p states in the spectrum of EB₁₂. The states of the first type (covalent intra-icosahedral B-B interactions, namely three-center bonds on the triangular faces of icosahedra) are responsible for the stabilization of individual B₁₂ polyhedra and depend little on their packing (B₁₂ sublattice structures) and the interaction of B₁₂ between each other (as well as with second sublattice atoms). They correspond to high k-dispersion bonding bands located below E_F and are similar for BB₁₂ and YB₁₂, see Fig. 1,2.

The states of the second group involve inter-icosahedral interactions. The nonbonding 2s,2p states of boron atoms surrounding the vacant sites in B₁₂ belong to third group. The narrow B' and B'' peaks in DOS correspond to it. These states form, in particular, a set of very flat partially occupied bands near the Fermi level (peak B'') with large effective masses. Consequently, EB₁₂ is a metal similar to -B₅₀ [7]. As distinct from the stable insulating state of -B₁₂ [5-8], where all mentioned above bands are fully occupied, the "deficiency" of electrons determining the metal-like properties of the hypothetical EB₁₂ is brought about by structural peculiarities of the modeling B₁₂ crystal. There are "empty spheres" in its bulk on the place of removed Y atoms. This intrinsic hole region accumulates some electrons (0.95 e according to our estimates) leading to partial devastation of the upper boron bands. DOS at the Fermi level ($N(E_F) = 6.177$ eV/cell) con-

sist of mainly B 2p component (96 percentage). The spectrum of EB_{12} contains a wide forbidden band of 1.36 eV (FG, direct transition in X point) comparable with the FG in YB_{12} (indirect Z gap of 1.43–1.70 eV [5–8]).

The main differences in band structures of YB_{12} and EB_{12} are determined by valence yttrium s,p,d-states hybridized with above mentioned inter-icosahedra and nonbonding B 2p states, peak C Fig. 2. For YB_{12} , the total width of the valence band is 12.98 eV, including two groups of fully occupied hybrid B 2s,2p bands of 2.82 and 8.89 eV widths separated by a pseudogap. These bands show the significant dispersion near the Fermi level. We also calculated a hypothetical dodecaboride BB_{12} (isoelectronic with YB_{12}), where an yttrium atom is replaced by an "additional" boron atom, see Fig. 1. It was found that (i) some s,p-states of the "additional" boron atom are located in the vicinity of E_F ; (ii) the system is of a metal-like character with a rather high density of states at the Fermi level ($N(E_F) = 3.034$ eV/cell), the main contribution being from the B 2p states (72 percentage).

As noted above, the experiments were reported recently, in which boron transforms from the usual non-metal to the SC state at high pressures (above 160 GPa), the crystal structure of the SC boron remains unknown [6]. This finding was explained [6] on the basis of the electron-phonon mechanism in the assumption that under high pressure boron undergoes structural transformations to a simple fcc B having a metal-like energy spectrum, with $N(E_F) = 0.154$ states/eV cell (lattice constant 2.44 Å) and the dominant contributions from the B 2p states (60 percentage). According to Table 2, the near-the Fermi level regions of our hypothetical systems EB_{12} and BB_{12} have a similar band structure. The former system can be interpreted as a model of elemental boron with a disordered lattice. The latter illustrates the role of inter-icosahedral boron atoms in crystal. This allows us to surmise that the observed [9] transition of the rhombohedral boron to the superconducting state may be due both to lattice disordering and partial frustration of the initial icosahedral units, when some boron atoms take inter-icosahedral positions as a result

of high pressure. Such processes can be more probable than the phase transformation of rhombohedral boron to the fcc structure proposed in [8] if we take into consideration the high cohesion properties of elemental boron [5–7].

3.2. YB_6

Fig. 1 presents the electronic band structure of Y hexaboride. The 10 occupied energy bands is made up by hybrid B 2s,p-states represented the inter- and intra-octahedral B-B bonds. The VB width in YB_6 (without quasi-core B 2s band) is about 11.80 eV. The highest fully occupied bands is due to $Bp_{x,y}$ -states formed by inter-octahedral interactions. They have strong dispersion along X direction due to the formation of hybrid Y-B bonds. The DOS spectrum has two maxima (A and B, Fig. 2), corresponding to hybrid states, formed by covalent B-B bonds inside and between B_6 clusters. This feature is typical for all CaB_6 like hexaborides [15–17].

The partially occupied band contains a considerable contribution from cation states and has also a large wave-vector dependence, which reflects the delocalized character of Y d states forming the bottom of the conductivity band.

It has been indicated that YB_{12} and YB_6 are the conventional low-temperature phonon-mediated BCS superconductors, review [3]. Thus, the important parameter is the orbital composition of $N(E_F)$. According to our data, the lowering of the transition temperature (7.1 K (YB_6) ! 4.7 K (YB_{12})) can be explained by a considerable decrease of contributions of Y d-states to $N(E_F)$ from 0.798 (YB_6 71 percentage) to 0.538 (YB_{12} , 35 percentage per atom in unit cell, Table 2).

3.3. YB_2 as compared with MgB_2

The electronic structures of layered AB_2 -like Mg and Y diborides are of a completely different, Fig. 3, 4. The peculiarities of the band structure of the SC MgB_2 are due to the B 2p states which form four ($2p_{x,y}$) and two (p_z) bands, Fig. 3. The $E(k)$ dependence for $B2p_{x,y}$ and $2p_z$ bands differs considerably. For $B2p_{x,y}$ like bands the most pronounced dispersion of $E(k)$ is observed along the direction $k_{x,y}$ ($\Gamma - K$ of the Brillouin

zone (BZ)). These bands are of the quasi two dimensional (2D) type. They form a flat zone along k_z ($\sim A$) and reflect the distribution of ($2p_{xy}$) states in the boron layers. These states make a considerable contribution to the $N(E_F)$ forming metallic properties of the diboride. E_F is located in the region of bonding states and, the conductivity of MgB_2 is due to hole carriers. Mg is ionized, the charge transfer takes place in the direction $Mg \rightarrow B$. $B2p_z$ -like bands are responsible for weaker (p_z) interactions. These 3D-type bands have the maximum dispersion in the direction k_z ($\sim A$). Mgs_p and Bs states are admixed to $B2p$ -like bands near the bottom of the VB and in the conduction band. Therefore the peculiarities of the electronic properties of MgB_2 are associated with the metal-like $2p$ states of boron atoms located in plane nets. These states determine the DOS in the vicinity of the Fermi level and is an important condition for superconductivity in MgB_2 and related phases [2,3,19-21]. Thus the crucial features of the band spectrum of MgB_2 for its superconducting properties (see also [2,3,19-21]) are: (i) the position of (p_{xy}) bands relative to E_F (the presence of hole p_{xy} -states); (ii) their dispersion in the direction $\sim A$ ($E \sim A$) is determined by the interaction between metal-boron layers); (iii) the value and orbital composition of $N(E_F)$ (the main contributions from boron \sim -states).

Let us compare the band structures of MgB_2 and YB_2 . The most obvious consequence of the metal variation ($MgB_2 \rightarrow YB_2$) is band filling change caused by the increased number of valence electrons. For YB_2 , the Fermi level is shifted towards a pseudogap between bonding and antibonding states. As a result, the near- E_F spectra of YB_2 and MgB_2 differ radically. For YB_2 , (i) (p_{xy}) boron bands are almost filled and the hole concentration is very small (near point A of the BZ, Fig. 3); (ii) the covalent d-p metal-boron bonding increases considerably and the $B2p$ -like bands are shifted downwards to point K (these interactions are also responsible for the appearance of pronounced dispersion of bands in the direction $\sim A$ and for 2D \rightarrow 3D transformation of the near- E_F states); (iii) the Y 4d band along the $\sim M$ is below E_F and these states give a large (

59 percentage) contribution to $N(E_F)$.

The 2D \rightarrow 3D transformation of the near- E_F states can be also traced by comparing the Fermi surfaces (FS) of MgB_2 and YB_2 , Fig. 3. For MgB_2 , $B2p_{xy}$ bands form two hole-like cylindrical Fermi surfaces around the $\sim A$ direction. The other tubular surfaces come from bonding (hole-like) and antibonding (electron-like) $B2p_z$ bands. By contrast, the FS of YB_2 consists of hole-like ellipsoids around the $\sim A$ line and 3D figures with electron-type conductivity. All these FSs are defined by mixed Y 4d- $B2p$ states. Thus, the absence of superconductivity in YB_2 can be accounted for (see also [21]) by the high energy shift of E_F , a considerable increase of Y 4d-component in $N(E_F)$, and the absence of (p_{xy}) hole states at $\sim A$, Fig. 3.

4. Conclusions

We presented the results of full-potential LMTO band structure calculations for yttrium dodeca- and hexaborides compared with layered non-superconducting YB_2 and the new "medium- T_c " SC MgB_2 diborides.

The band structures of boron-rich crystals are determined by the complicated intraatomic bonds including intra and between boron polyhedra (B_{12} for YB_{12} and B_6 for YB_6) and direct Y-B bonds. The DOS at the Fermi level for the low-temperature SC YB_{12} and YB_6 has a similar composition and includes the large contribution of Y 4d-states. The lowering of T_c ($YB_6 \rightarrow YB_{12}$) can be explained by a considerable decrease in main contributions of Y d-states to $N(E_F)$. We performed also band structure calculations for two hypothetical structures: "dodecaboride" with an empty Y-sublattice (EB_{12}) and the icosahedral phase (BB_{12}), which is a result of the Y \rightarrow B substitution. Both crystals are metals with high DOS at the Fermi level. We speculate that the observed [9] transition of the rhombohedral \sim -boron to the superconducting state can be due to both lattice disordering and partial frustration of the initial icosahedral units as a result of high pressure. Such processes can be more energetically favorable than the phase transformation of rhombohedral \sim -boron to the

fcc structure proposed in [8].

Quite different are the band structures of layered AlB_2 -like Mg and Y diborides. They are determined by intra- and interlayer interactions of plane (Mg,Y) and boron nets. In contrast to MgB_2 , for YB_2 the increase of covalent d-p bonding leads to the downward shift of $B2p_z$ bands, larger dispersion of bands in the direction $\Gamma-A$ and 2D \rightarrow 3D band transformation near E_F . The most crucial changes are connected with the increase of electron numbers resulting in the almost filled (p_{xy}) boron bands. The hole (p_{xy}) bands are absent at point and the density of states at the Fermi level is mainly defined by Y 4d states, so these band structure peculiarities may be considered to be responsible for the absence of medium T_C superconductivity in YB_2 .

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Table 1

Transition temperatures (T_c , K), structure type and lattice constants (Å) YB_{12} , YB_6 , YB_2 and MgB_2 . a and c are lattice parameters from [10], a and c are lattice parameters from our self-consistent data.

Boron	T_c	Structure type (space group)	a	c	a	c
YB_{12}	4.7	UB_{12} (Fm $3m$)	7.5000	–	7.5223	–
YB_6	7.1	CaB_6 (Pm $3m$)	4.1132	–	4.1554	–
YB_2		AB_2 (P $6/mmm$)	3.3036	3.8427	3.2116	4.0080
MgB_2	40	AB_2 (P $6/mmm$)	3.083	3.521	3.0487	3.4664

Table 2

Total and site-projected 1-decomposed DOS at the Fermi level (state/eV/cell) for borides.

Boride	Total	M s	M p	M d	B s	B p
YB_{12}	1.458	0.005	0.003	0.532	0.033	0.885
EB_{12}	6.177	0.240			0.033	5.904
BB_{12}	3.034	0.743	0.119		0.109	2.063
YB_6	1.130	0.017	0.020	0.798	0.001	0.294
YB_2	1.665	0.042	0.106	0.983	0.006	0.528
MgB_2	0.719	0.040	0.083	0.138	0.007	0.448

Figures.

Fig.1. Band structures of YB_{12} (I), EB_{12} (II), BB_{12} (III) and YB_6 (IV).

Fig.2. Total and partial DOS (1-s, 2-p, 3-d) for YB_{12} , EB_{12} and YB_6 .

Fig.3. Band structure and Fermi surface for YB_2 (I) and MgB_2 (II).

Fig.4. Total and partial DOS (1-s, 2-p, 3-d) for YB_2 (I) and MgB_2 (II).

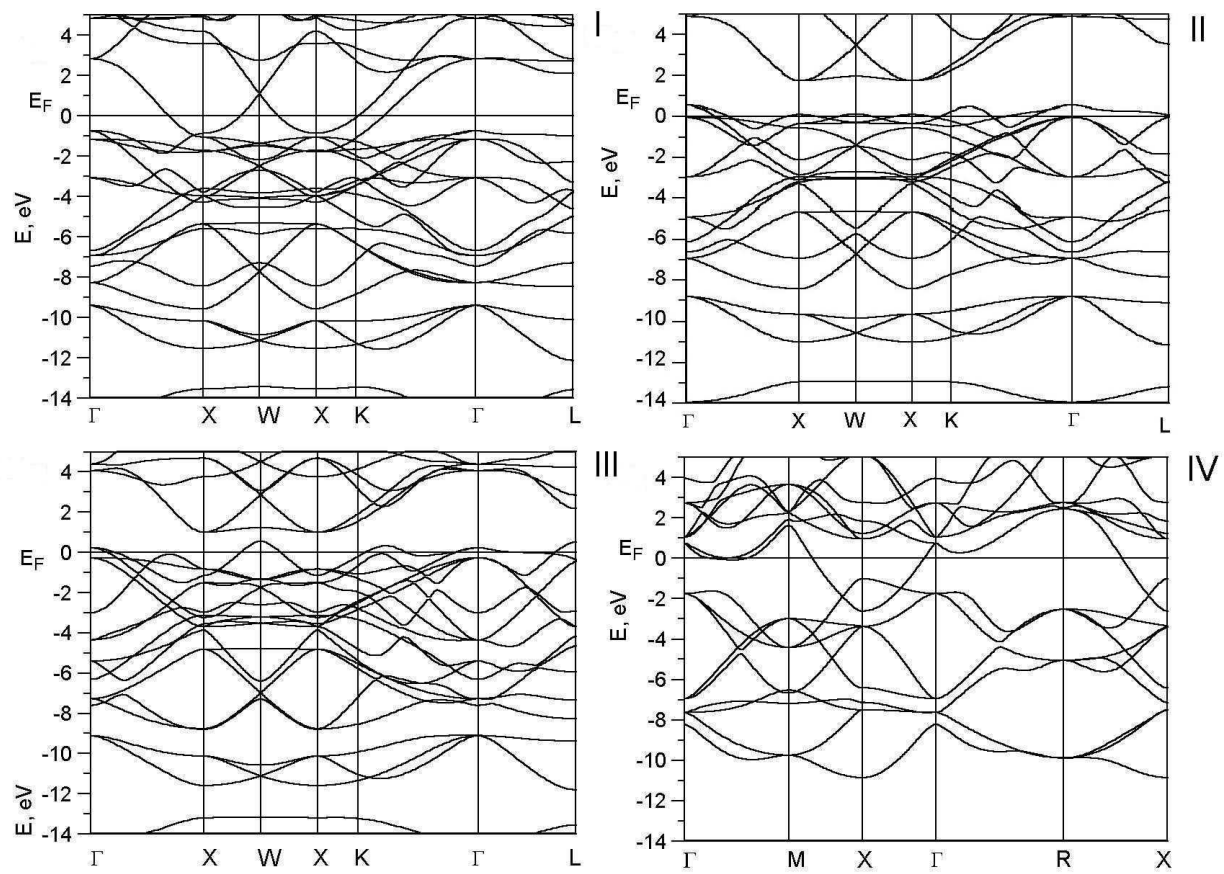


Fig.1.

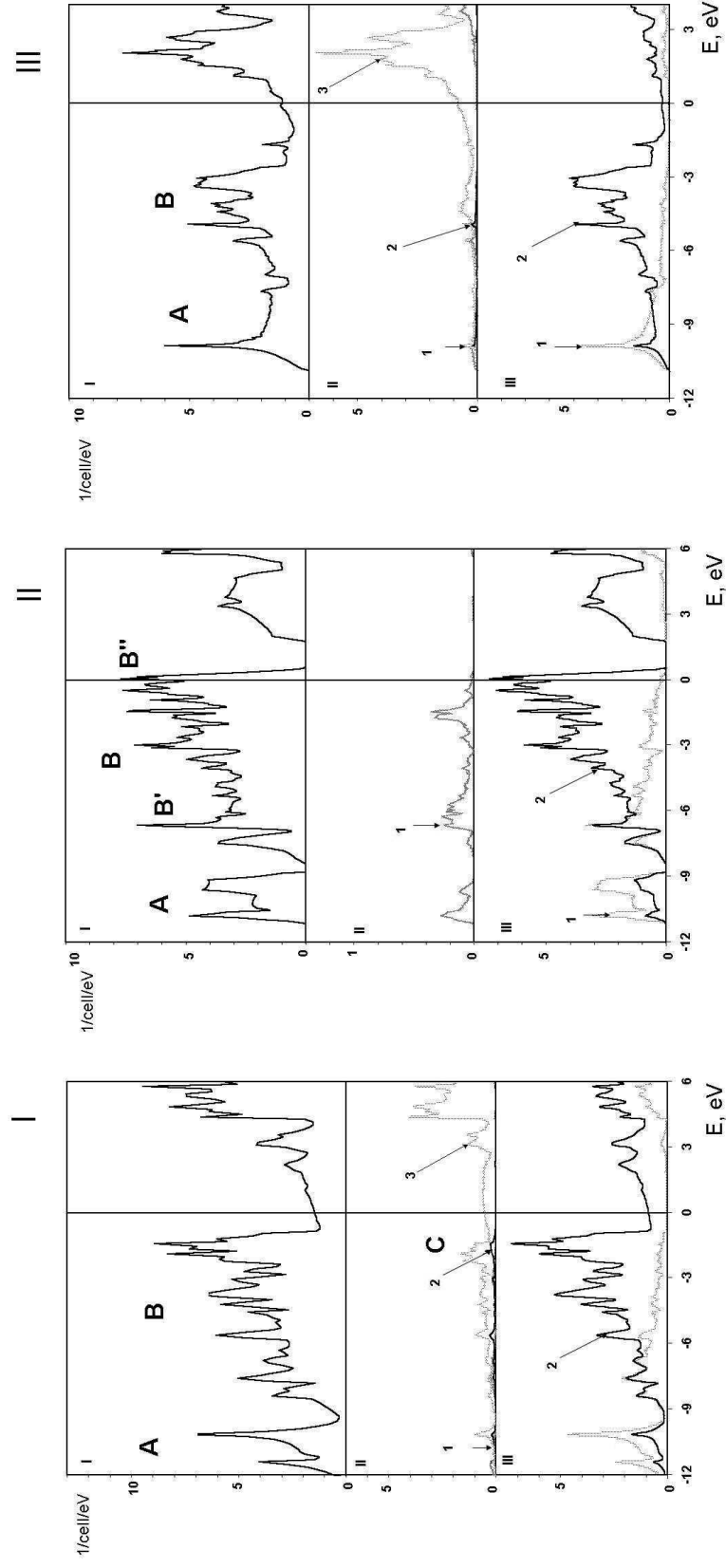
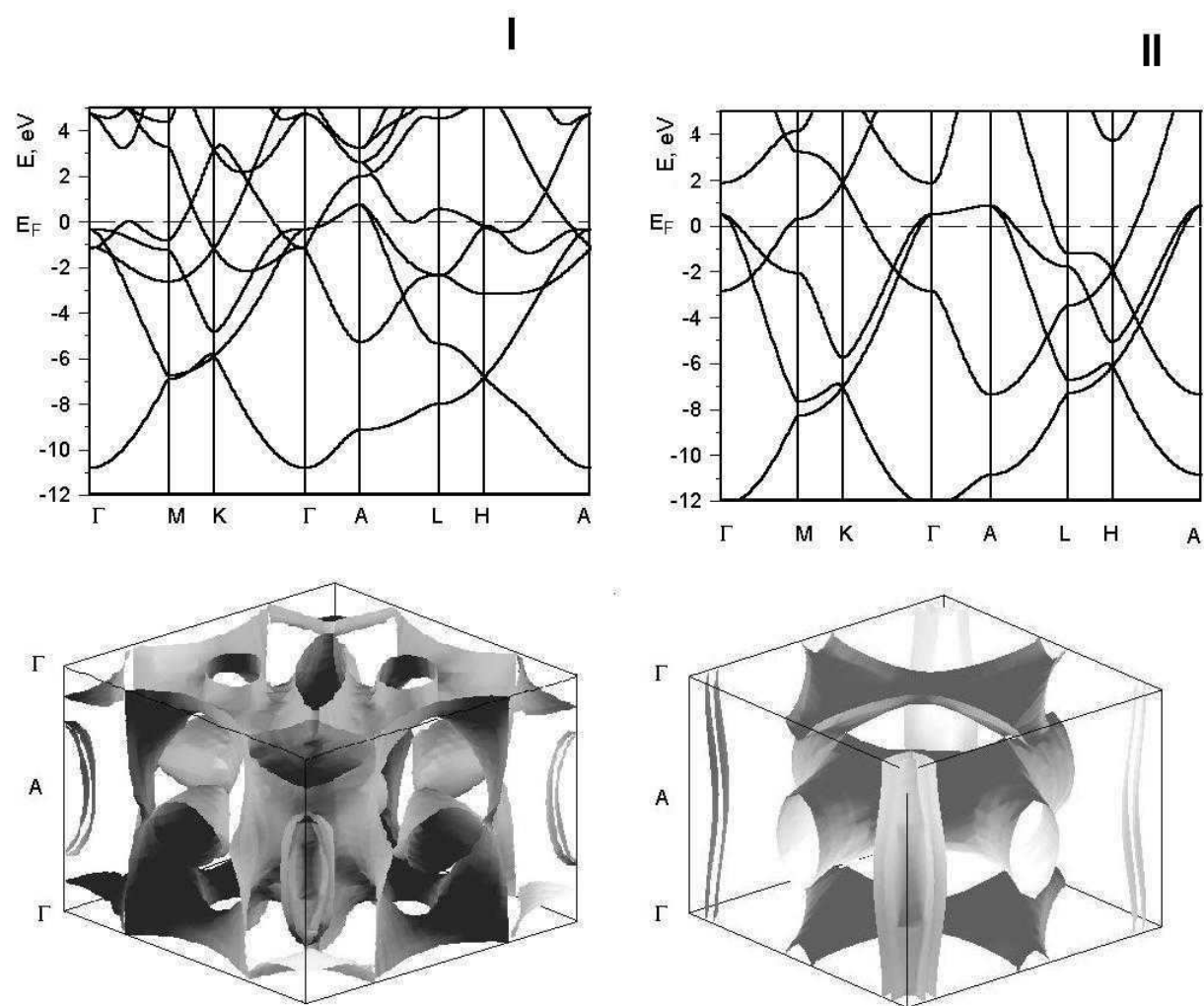


Fig.2.

**Fig.3.**

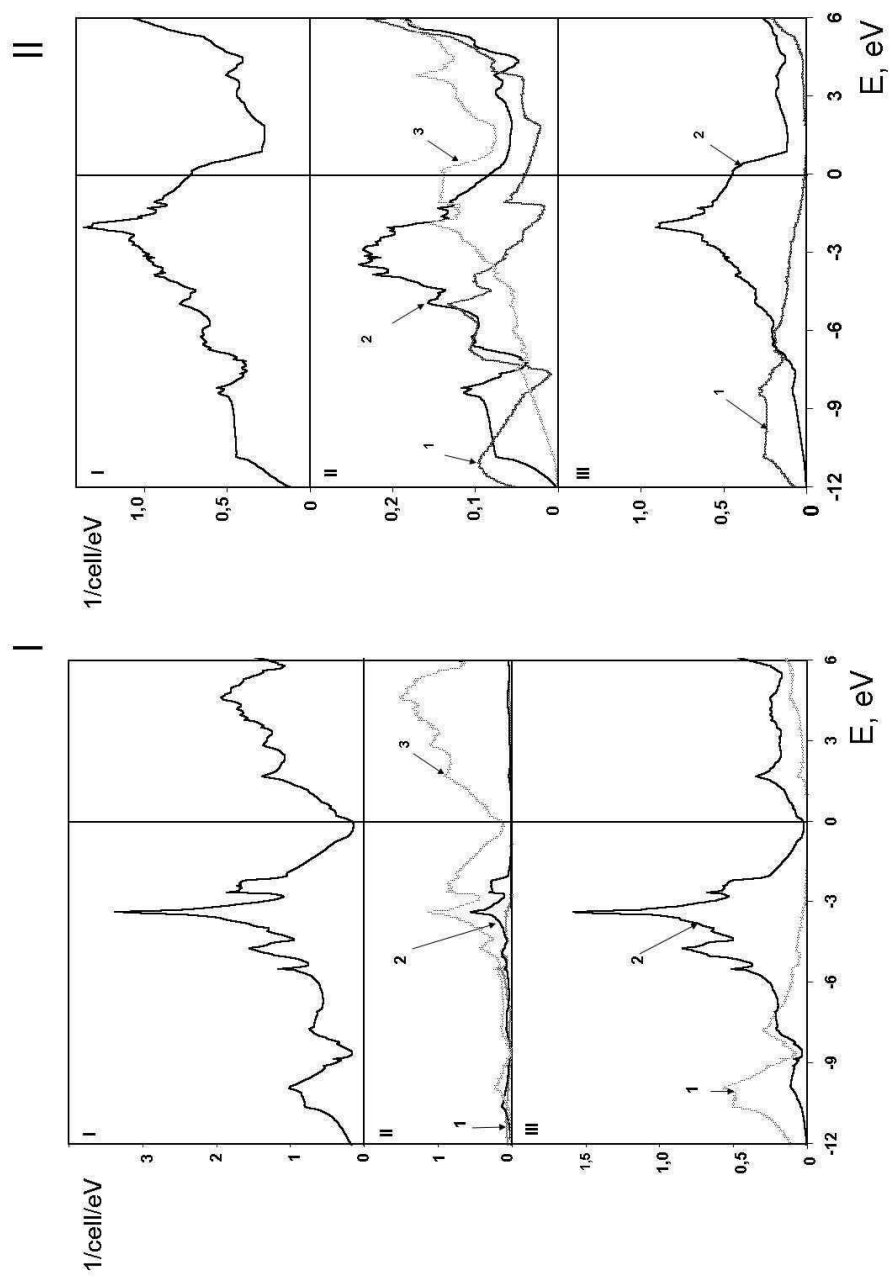


Fig.4.